

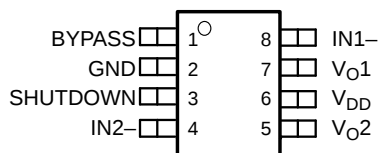


150-mW STEREO AUDIO POWER AMPLIFIER

FEATURES

- 150 mW Stereo Output
- PC Power Supply Compatible
 - Fully Specified for 3.3 V and 5 V Operation
 - Operation to 2.5 V
- Pop Reduction Circuitry
- Internal Mid-Rail Generation
- Thermal and Short-Circuit Protection
- Surface-Mount Packaging
 - PowerPAD™ MSOP
- Pin Compatible With LM4881

DGN PACKAGE
(TOP VIEW)

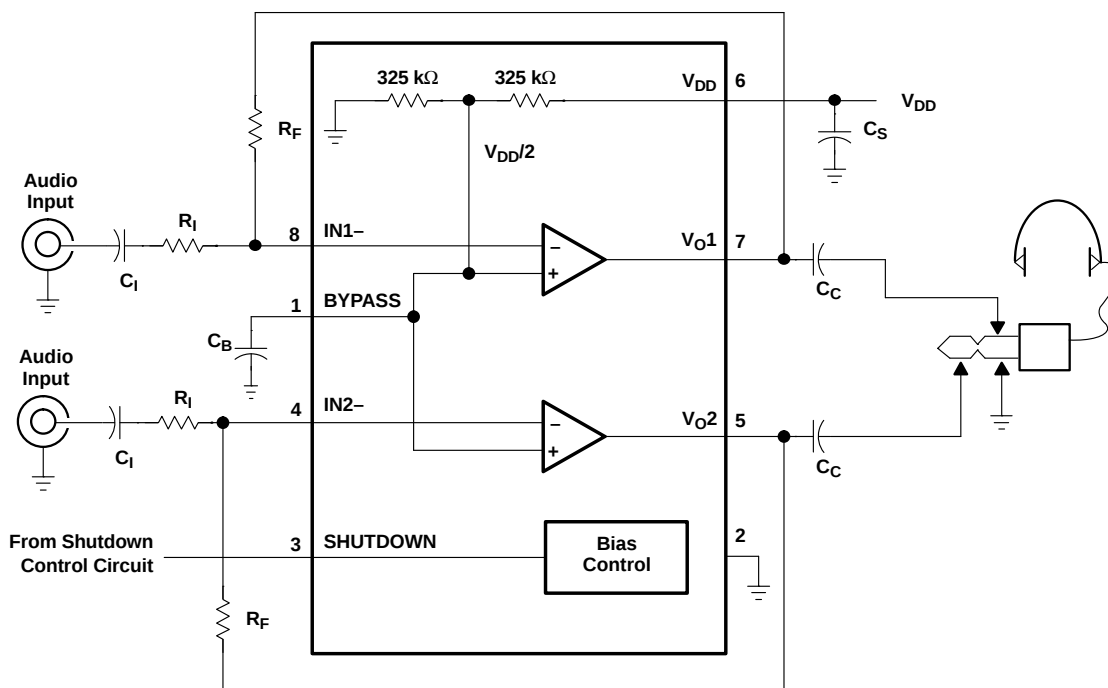


DESCRIPTION

The TPA102 is a stereo audio power amplifier packaged in an 8-pin PowerPAD™ MSOP package capable of delivering 150 mW of continuous RMS power per channel into 8-Ω loads. Amplifier gain is externally configured by means of two resistors per input channel and does not require external compensation for settings of 1 to 10.

THD+N when driving an 8-Ω load from 5 V is 0.1% at 1 kHz, and less than 2% across the audio band of 20 Hz to 20 kHz. For 32-Ω loads, the THD+N is reduced to less than 0.06% at 1 kHz, and is less than 1% across the audio band of 20 Hz to 20 kHz. For 10-kΩ loads, the THD+N performance is 0.01% at 1 kHz, and less than 0.02% across the audio band of 20 Hz to 20 kHz.

TYPICAL APPLICATION CIRCUIT



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

AVAILABLE OPTIONS

T_A	PACKAGED DEVICE	MSOP Symbolization
	MSOP ⁽¹⁾	
-40°C to 85°C	TPA102DGN	TI AAC

(1) The DGN package is available in left-ended tape and reel only (e.g., TPA102DGNR).

Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
BYPASS	1	I	Tap to voltage divider for internal mid-supply bias supply. Connect to a 0.1 μ F to 1 μ F low ESR capacitor for best performance.
GND	2	I	GND is the ground connection.
IN1–	8	I	IN1– is the inverting input for channel 1.
IN2–	4	I	IN2– is the inverting input for channel 2.
SHUTDOWN	3	I	Puts the device in a low quiescent current mode when held high.
V_{DD}	6	I	V_{DD} is the supply voltage terminal.
V_{O1}	7	O	V_{O1} is the audio output for channel 1.
V_{O2}	5	O	V_{O2} is the audio output for channel 2.
Thermal Pad			

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	UNIT
V_{DD} Supply voltage	6 V
V_I Input voltage	–0.3 V to $V_{DD} + 0.3$ V
Continuous total power dissipation	Internally limited
T_J Operating junction temperature range	–40°C to 150°C
T_{stg} Storage temperature range	–65°C to 150°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DGN	2.14 W ⁽¹⁾	17.1 mW/°C	1.37 W	1.11 W

(1) See the Texas Instruments document, *PowerPAD Thermally Enhanced Package Application Report* (SLMA002), for more information on the PowerPAD package. The thermal data was measured on a PCB layout based on the information in the section entitled *Texas Instruments Recommended Board for PowerPAD* on page 33 of the beforementioned document.

RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
V _{DD} Supply voltage	2.5	5.5	V
T _A Operating free-air temperature	-40	85	°C
V _{IH} High-level input voltage (SHUTDOWN)	0.80 × V _{DD}		V
V _{IL} Low-level input voltage (SHUTDOWN)	0.25 × V _{DD}		V

DC ELECTRICAL CHARACTERISTICS

at T_A = 25°C, V_{DD} = 2.5 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OO} Output offset voltage (measured between output and BYPASS terminal)	A _v = 2 V/V			10	mV
PSRR Power supply rejection ratio	V _{DD} = 3.2 V to 3.4 V		83		dB
I _{DD} Supply current	SHUTDOWN = 0 V		1.5	3	mA
I _{DD(SD)} Supply current in SHUTDOWN mode	SHUTDOWN = V _{DD}		10	50	μA
Z _I Input impedance			>1		MΩ

AC OPERATING CHARACTERISTICS

V_{DD} = 3.3 V, T_A = 25°C, R_L = 8Ω

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P _O Output power (each channel)	THD ≤ 0.1%		70 ⁽¹⁾		mW
THD+N Total harmonic distortion + noise	P _O = 70 mW, 20–20 kHz		2%		
B _{OM} Maximum output power BW	G = 10, THD <5%		>20		kHz
Phase margin	Open loop		58°		
Supply ripple rejection ratio	f = 1 kHz		68		dB
Channel/channel output separation	f = 1 kHz		86		dB
SNR Signal-to-noise ratio	P _O = 100 mW		100		dB
V _n Noise output voltage			9.5		μV(rms)

(1) Measured at 1kHz

DC ELECTRICAL CHARACTERISTICS

at T_A = 25°C, V_{DD} = 5.5 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OO} Output offset voltage	A _v = 2 V/V			10	mV
PSRR Power supply rejection ratio	V _{DD} = 4.9 V to 5.1 V		76		dB
I _{DD} Supply current	SHUTDOWN = 0 V		1.5	3	mA
I _{DD(SD)} Supply current in SHUTDOWN mode	SHUTDOWN = V _{DD}		60	100	μA
I _{IH} High-level input current (SHUTDOWN)	V _{DD} = 5.5 V, V _I = V _{DD}			1	μA
I _{IL} Low-level input current (SHUTDOWN)	V _{DD} = 5.5 V, V _I = 0 V			1	μA
Z _I Input impedance			>1		MΩ

AC OPERATING CHARACTERISTICS $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 8\Omega$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O	Output power (each channel)	THD $\leq 0.1\%$		70 ⁽¹⁾		mW
THD+N	Total harmonic distortion + noise	$P_O = 150\text{ mW}$, 20–20 kHz		2%		
B_{OM}	Maximum output power BW	$G = 10$, THD $< 5\%$		> 20		kHz
	Phase margin	Open loop		56°		
	Supply ripple rejection ratio	$f = 1\text{ kHz}$		68		dB
	Channel/Channel output separation	$f = 1\text{ kHz}$		86		dB
SNR	Signal-to-noise ratio	$P_O = 150\text{ mW}$		100		dB
V_n	Noise output voltage			9.5		$\mu\text{V(rms)}$

(1) Measured at 1kHz

AC OPERATING CHARACTERISTICS $V_{DD} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 32\Omega$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O	Output power (each channel)	THD $\leq 0.1\%$		40 ⁽¹⁾		mW
THD+N	Total harmonic distortion + noise	$P_O = 30\text{ mW}$, 20–20 kHz		0.5%		
B_{OM}	Maximum output power BW	$A_V = 10$, THD $< 2\%$		> 20		kHz
	Phase margin	Open loop		58°		
	Supply ripple rejection ratio	$f = 1\text{ kHz}$		68		dB
	Channel/channel output separation	$f = 1\text{ kHz}$		97		dB
SNR	Signal-to-noise ratio	$P_O = 100\text{ mW}$		100		dB
V_n	Noise output voltage			9.5		$\mu\text{V(rms)}$

(1) Measured at 1kHz

AC OPERATING CHARACTERISTICS $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 32\Omega$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O	Output power (each channel)	THD $\leq 0.1\%$		40 ⁽¹⁾		mW
THD+N	Total harmonic distortion + noise	$P_O = 60\text{ mW}$, 20–20 kHz		0.4%		
B_{OM}	Maximum output power BW	$A_V = 10$, THD $< 2\%$		> 20		kHz
	Phase margin	Open loop		56°		
	Supply ripple rejection ratio	$f = 1\text{ kHz}$		68		dB
	Channel/channel output separation	$f = 1\text{ kHz}$		97		dB
SNR	Signal-to-noise ratio	$P_O = 150\text{ mW}$		100		dB
V_n	Noise output voltage			9.5		$\mu\text{V(rms)}$

(1) Measured at 1kHz

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
THD+N	Total harmonic distortion plus noise	vs Frequency
		1, 2, 4, 5, 7, 8, 10, 11, 13, 14, 16, 17, 34, 36
		vs Power output
		3, 6, 9, 12, 15, 18
	Power supply rejection ratio	vs Frequency
		19, 20
V_n	Output noise voltage	vs Frequency
		21, 22
	Crosstalk	vs Frequency
		23-26, 37, 38
	Mute attenuation	vs Frequency
		27, 28
	Open-loop gain	vs Frequency
	Phase margin	29, 30
	Output power	vs Load resistance
		31, 32
I_{DD}	Supply current	vs Supply voltage
		33
SNR	Signal-to-noise ratio	vs Voltage gain
		35
	Closed-loop gain	vs Frequency
	Phase	39-44
	Power dissipation	vs Output power
		45, 46

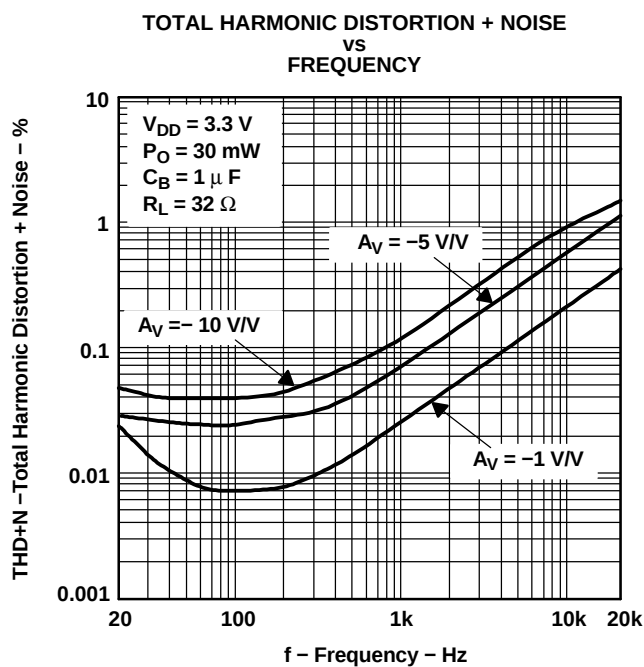


Figure 1.

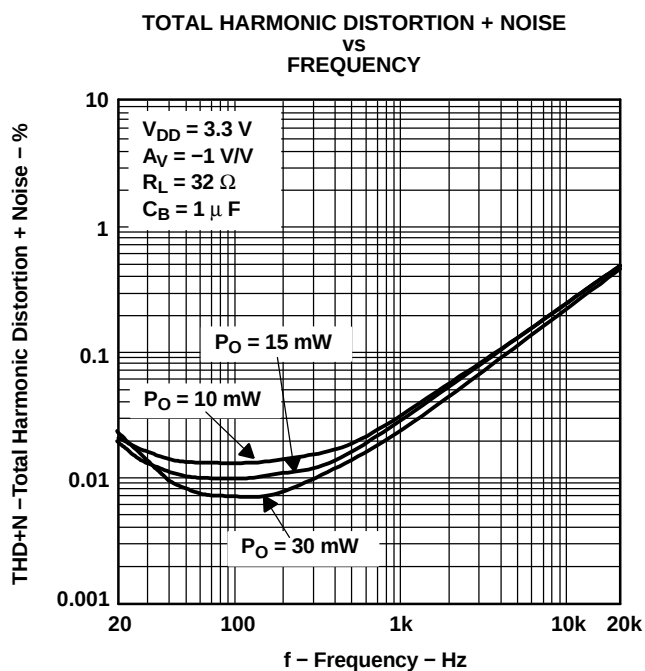


Figure 2.

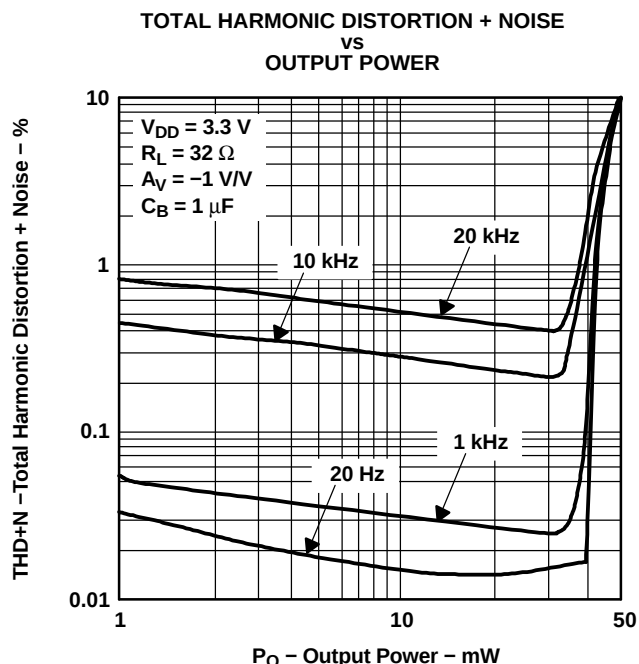


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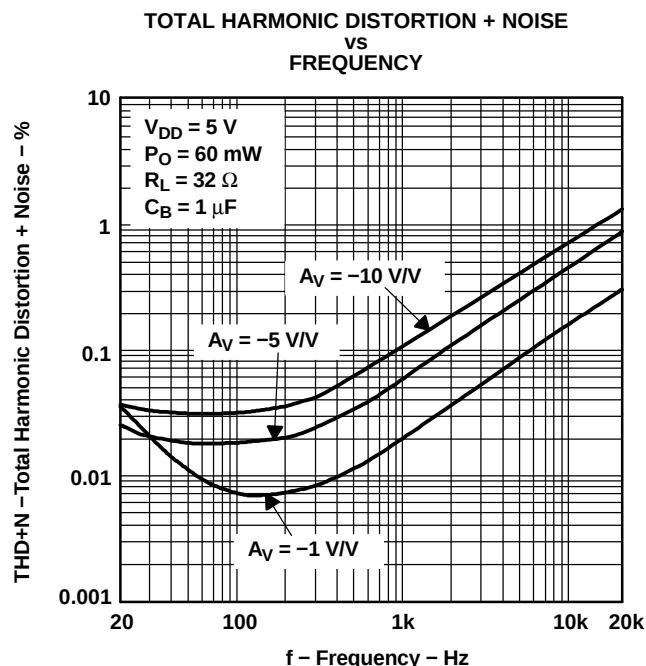


Figure 4.

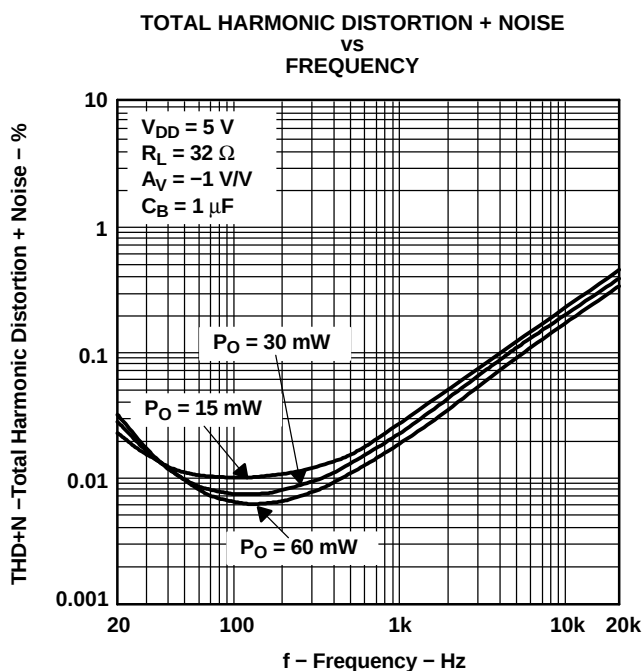


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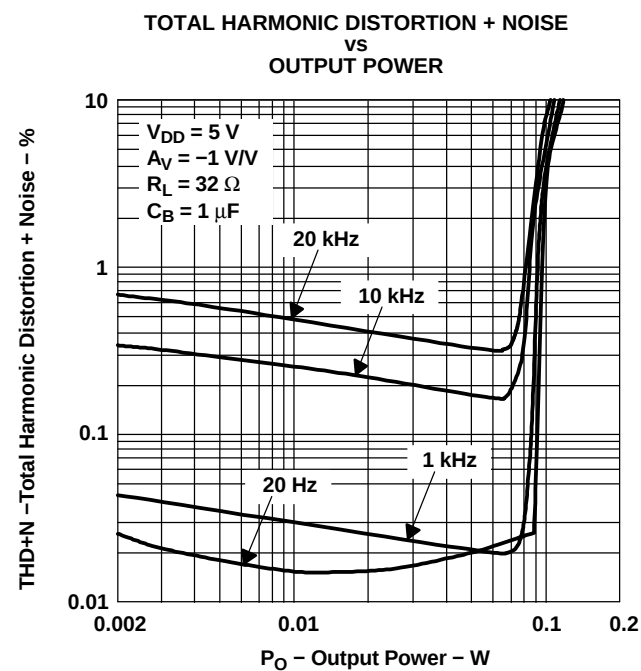


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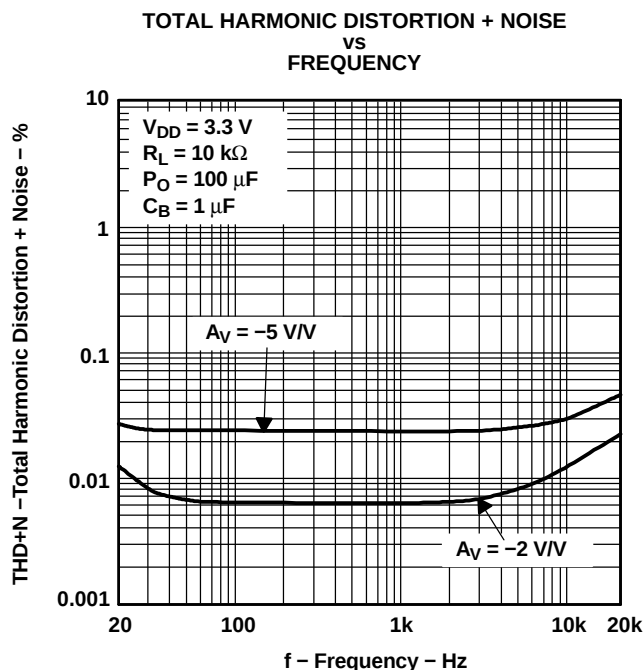


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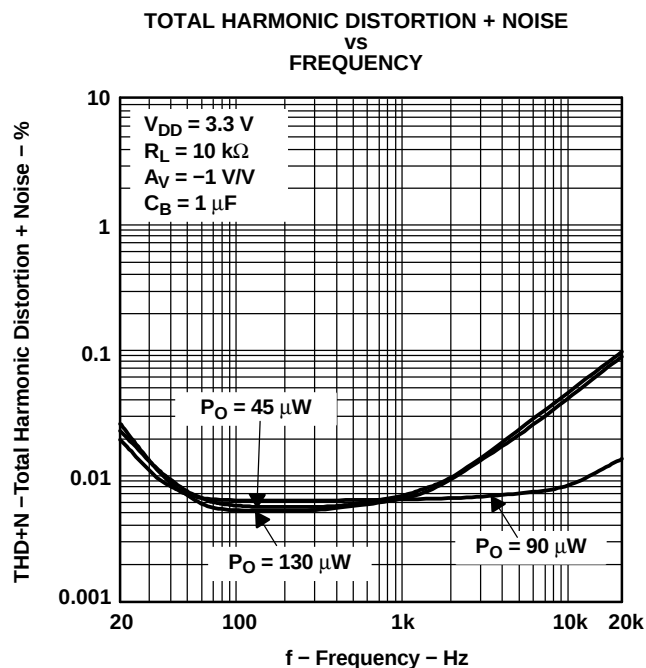


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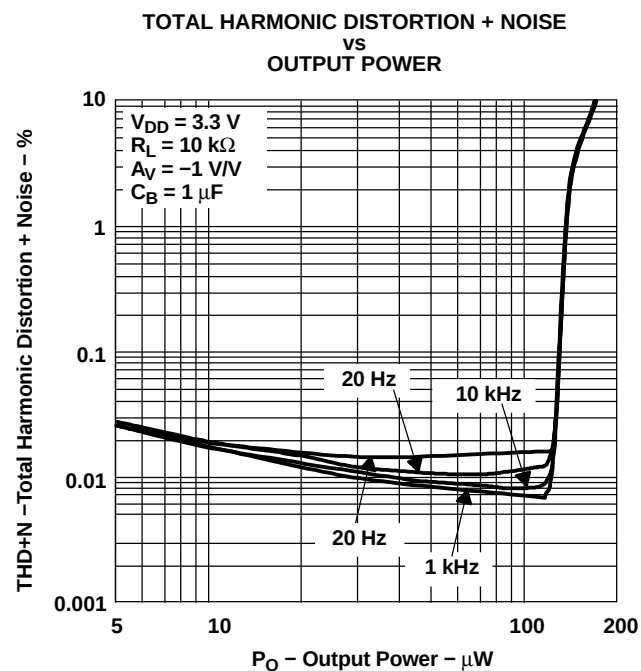


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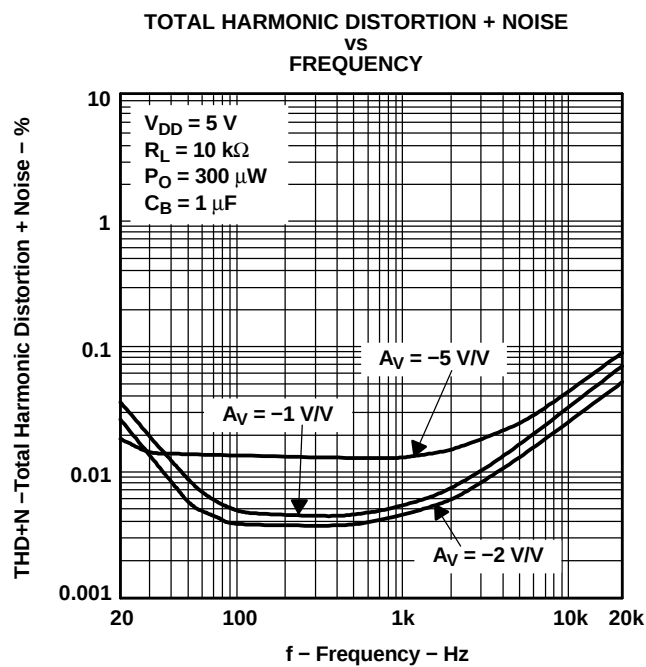


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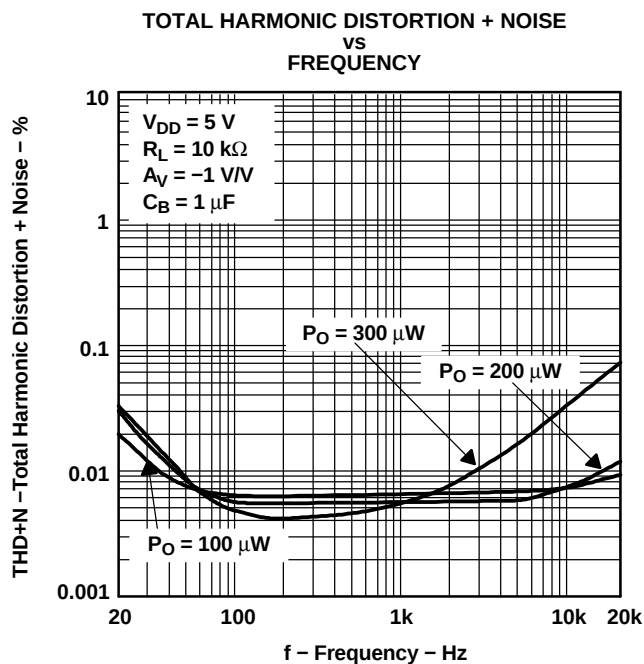


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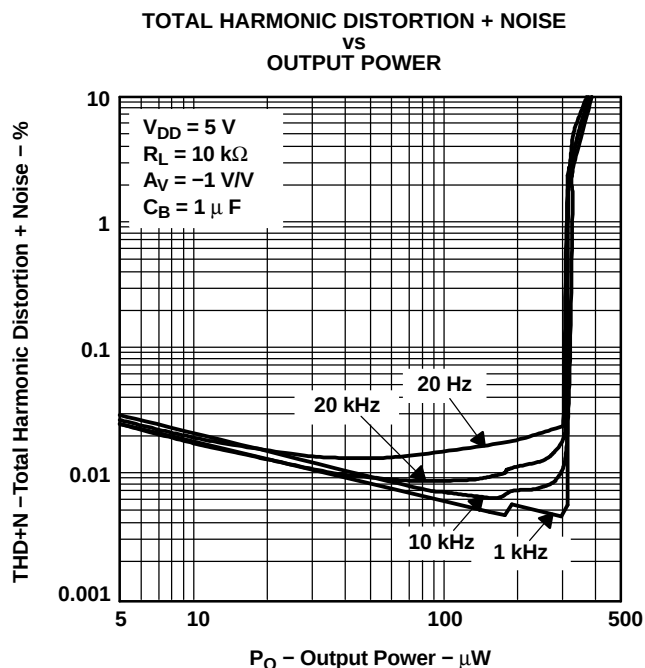


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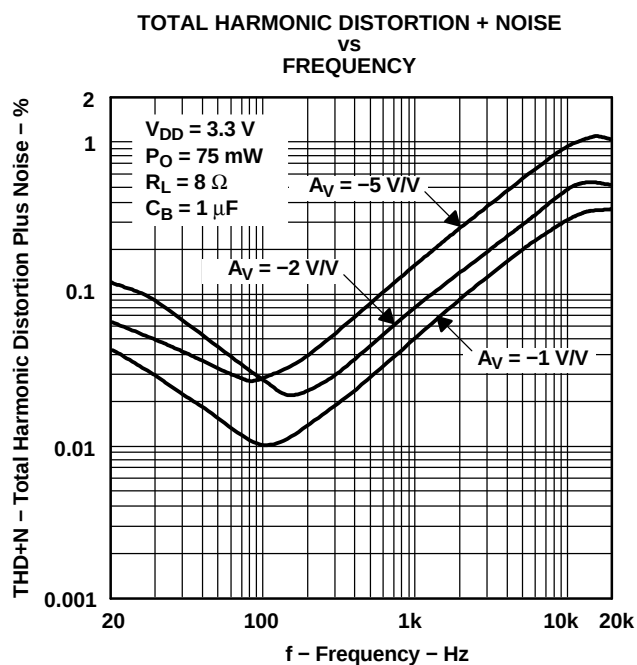


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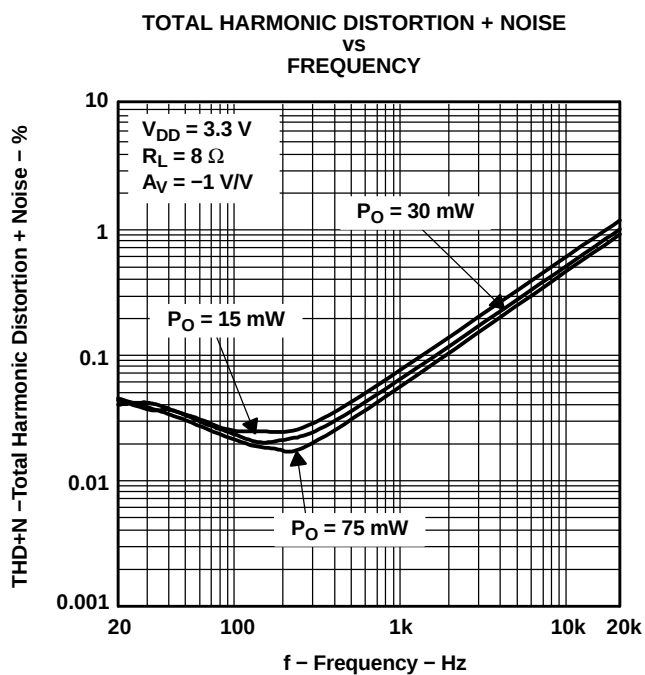


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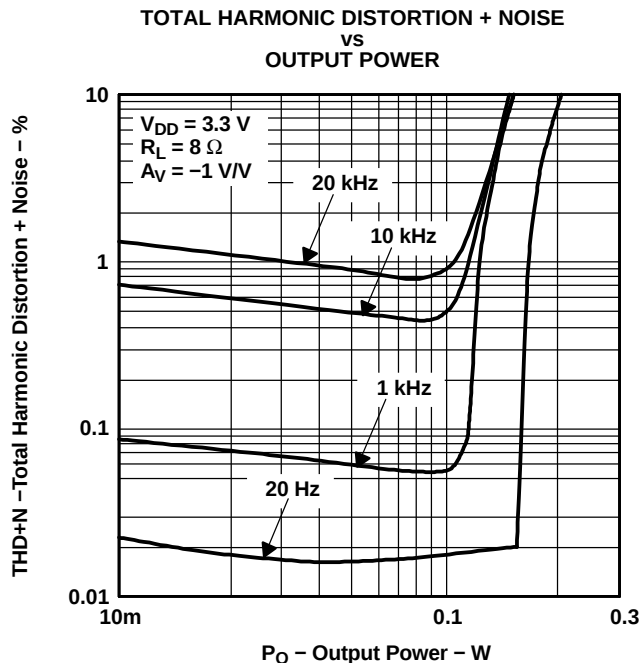


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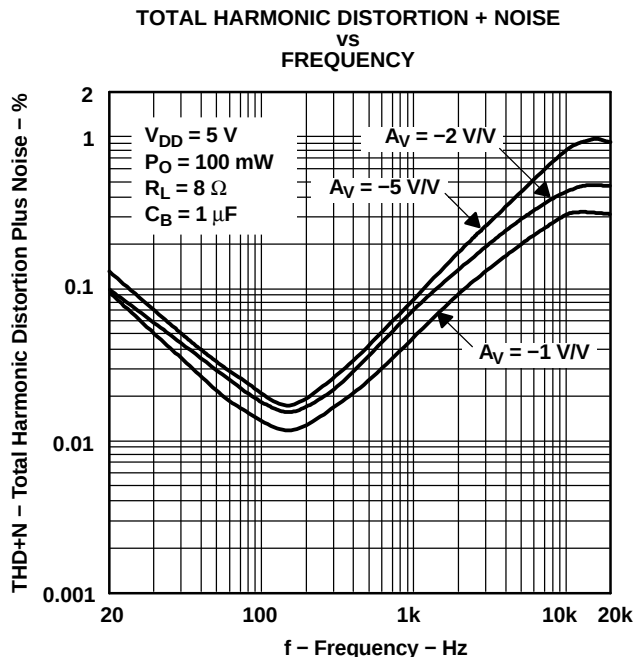


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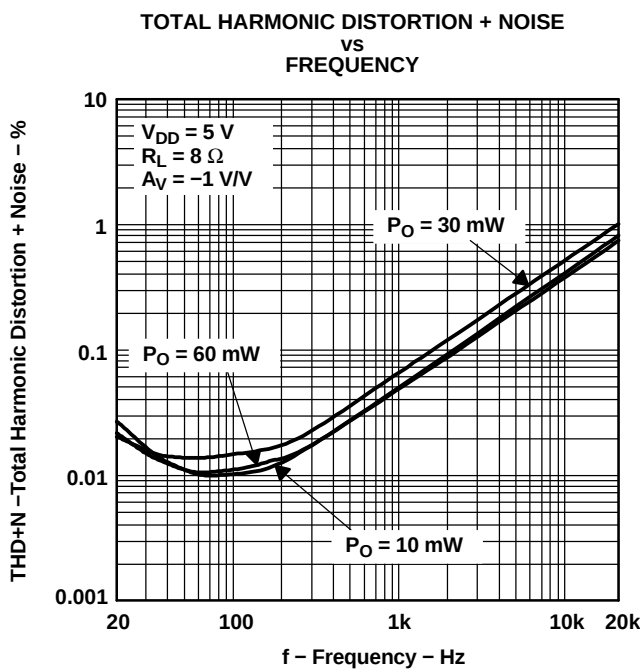


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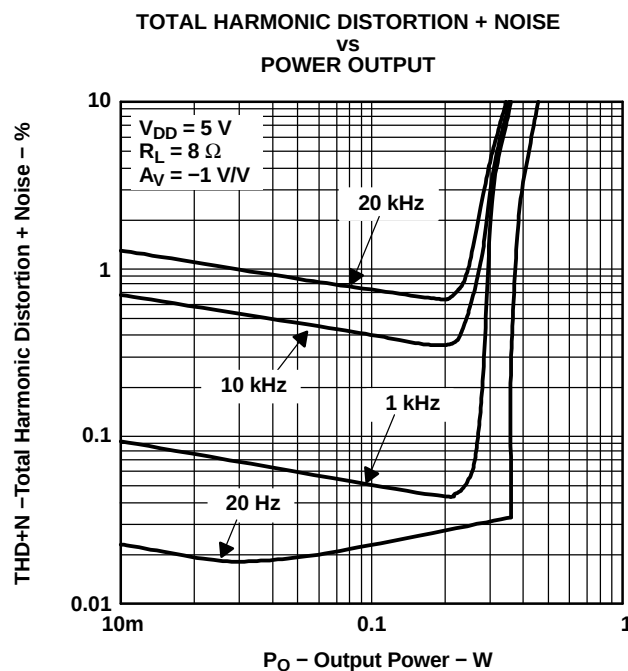


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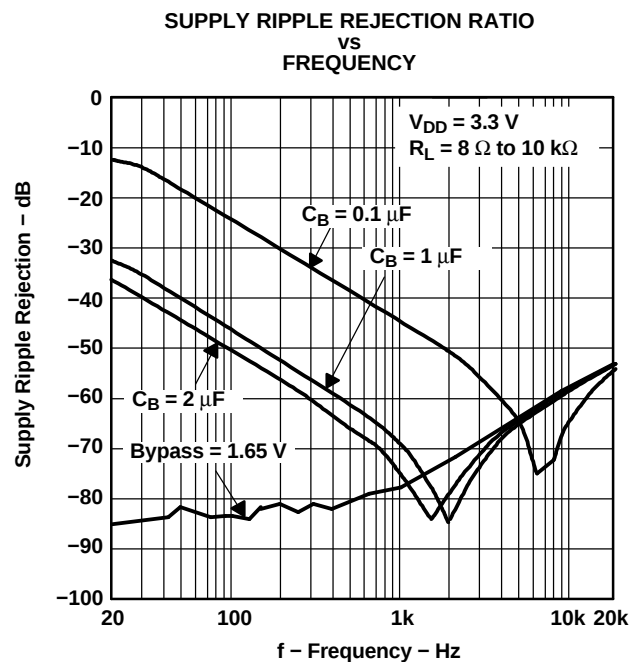


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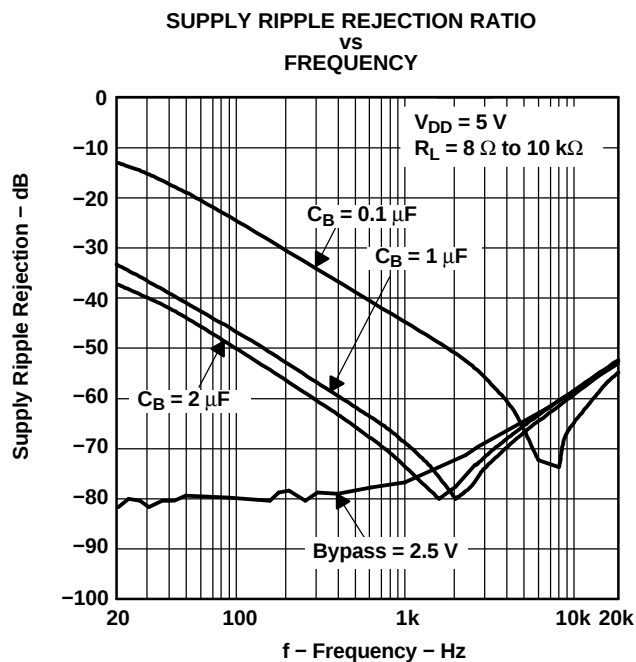


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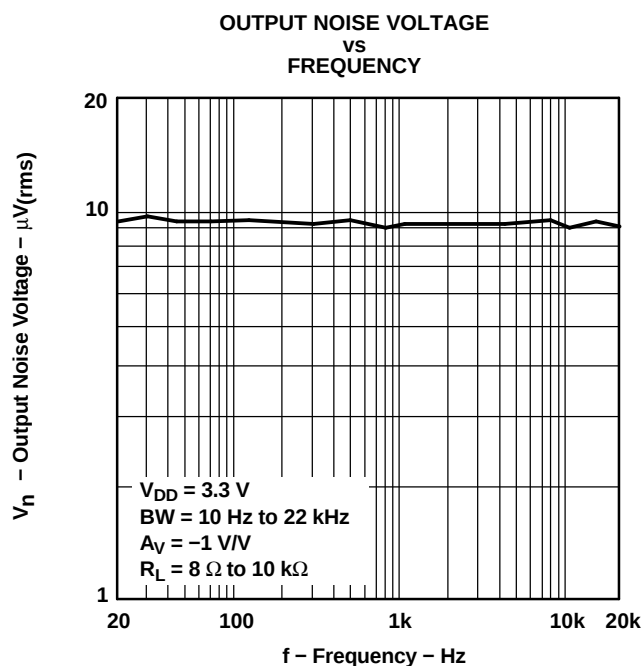


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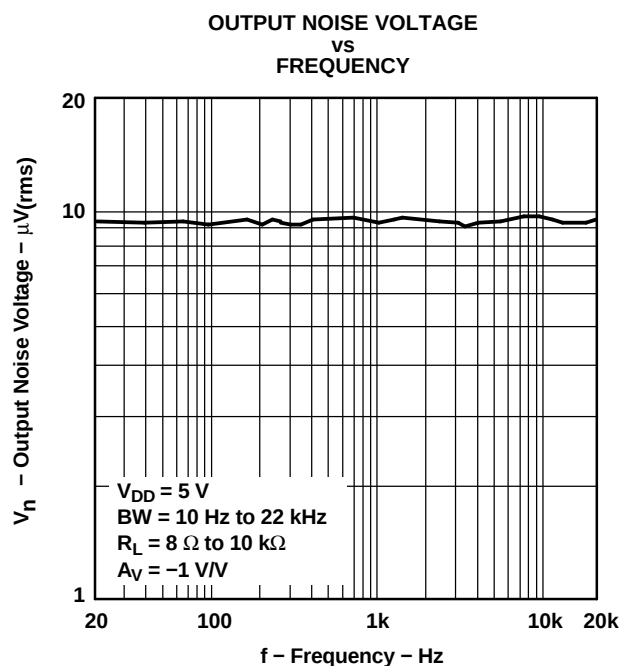


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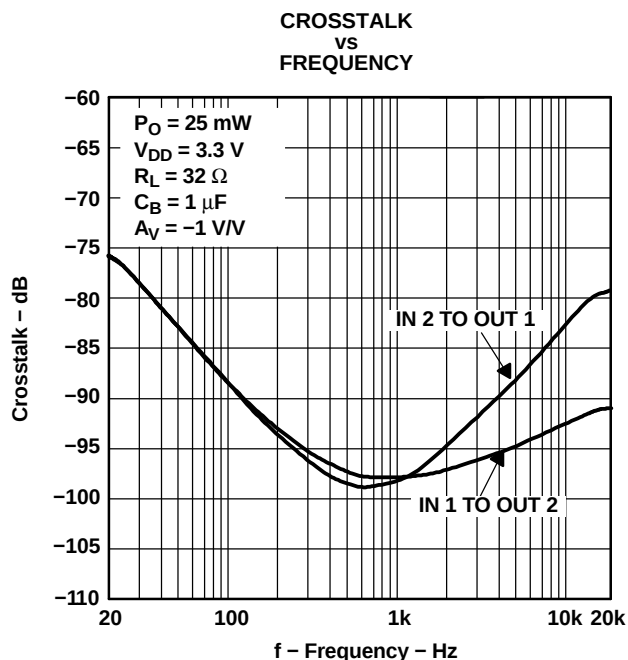


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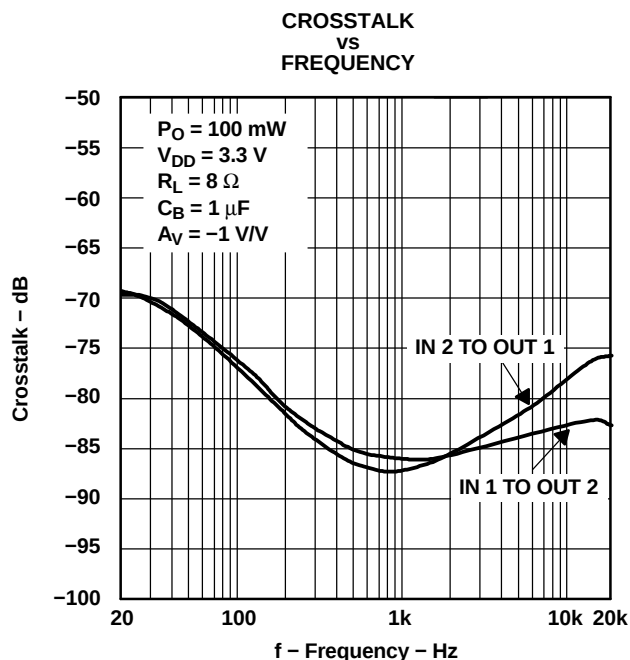


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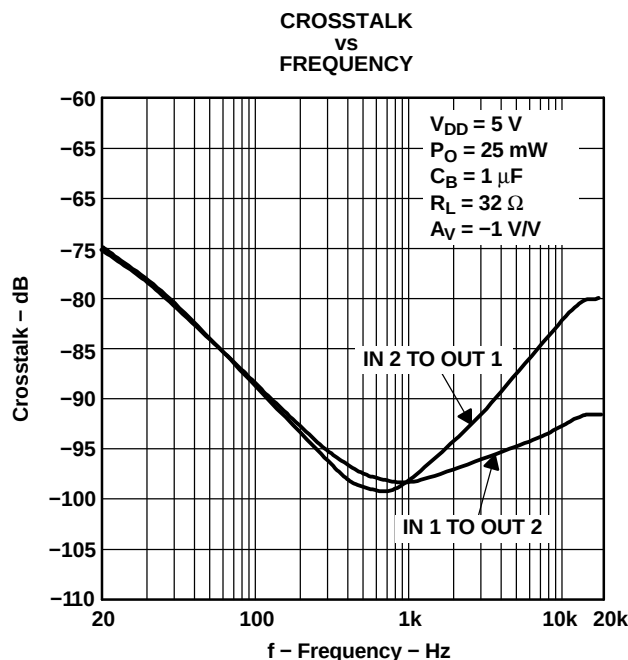


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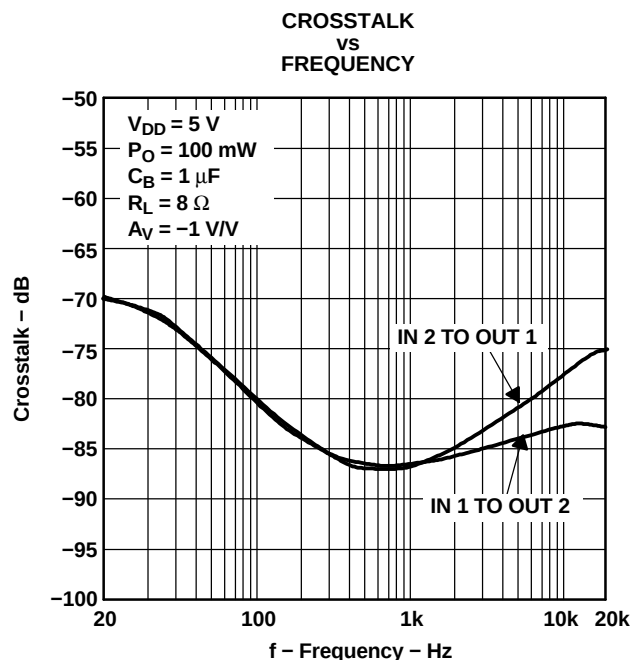


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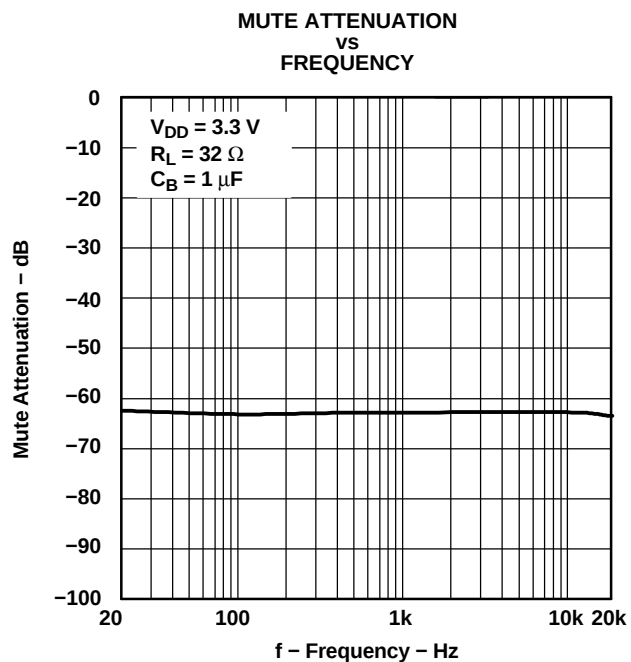


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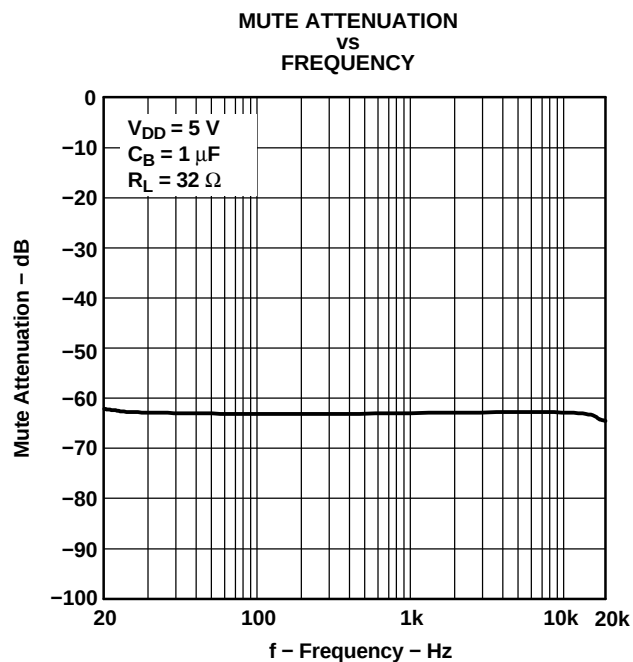


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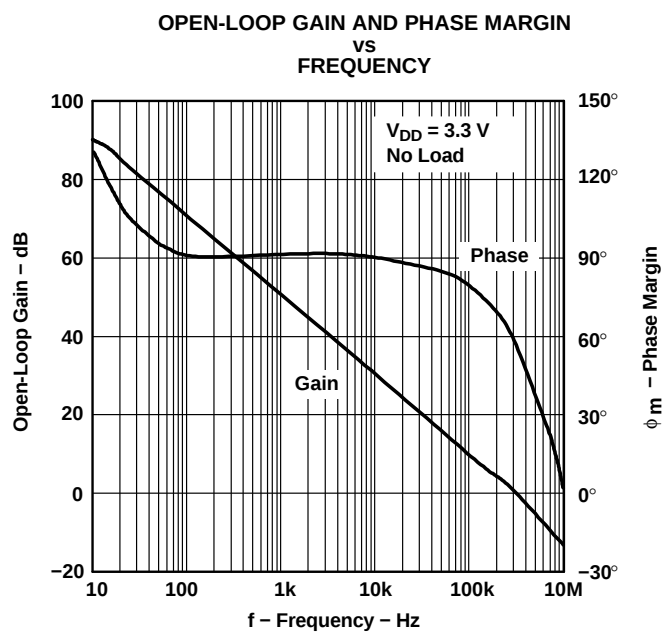


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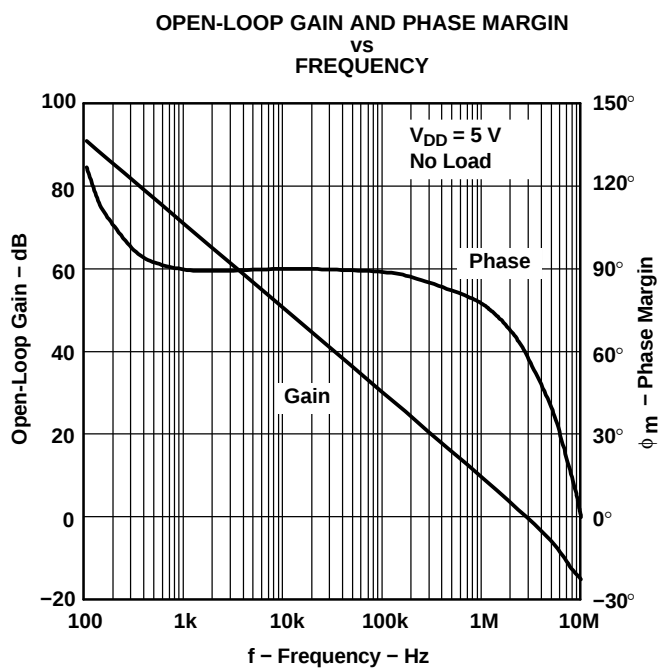


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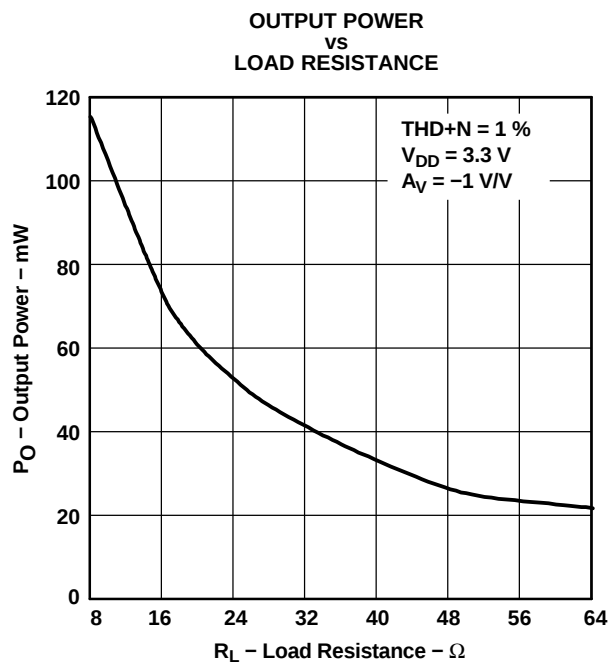


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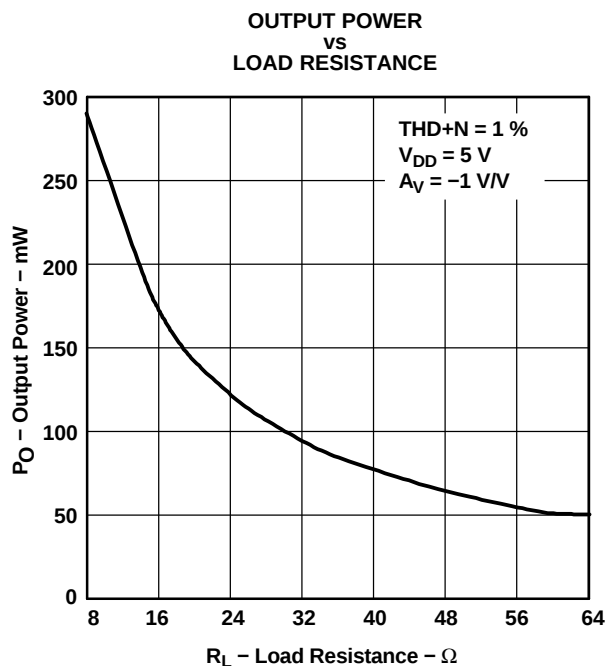


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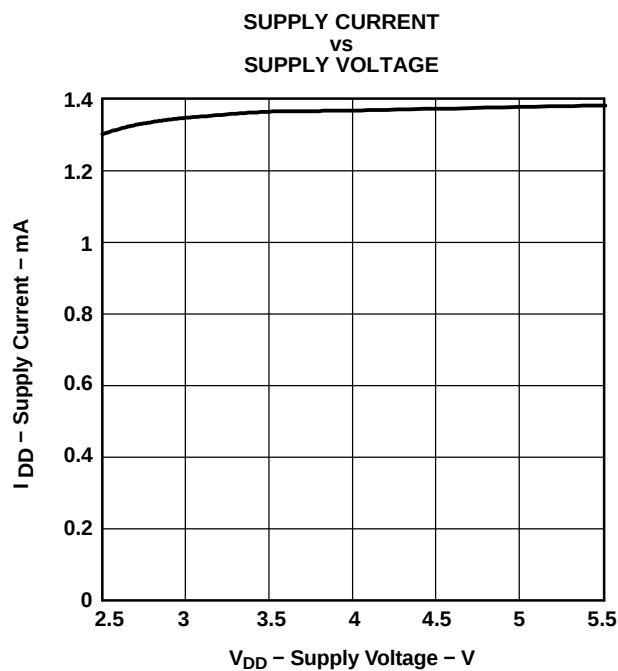


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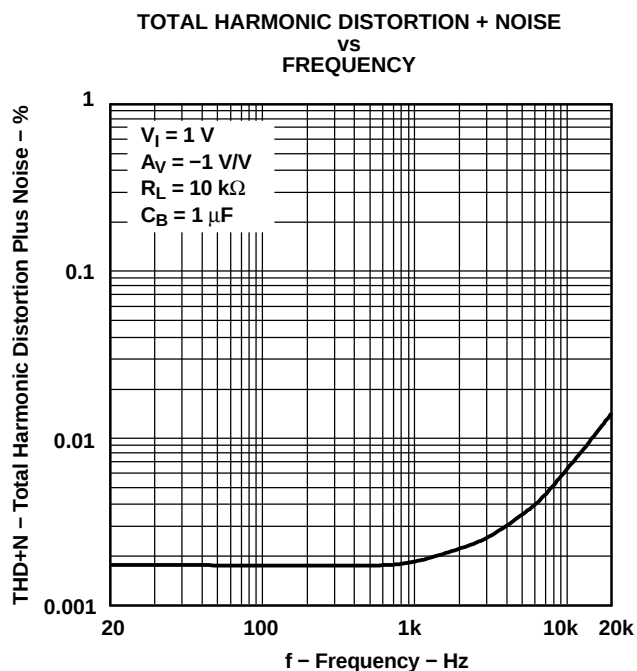


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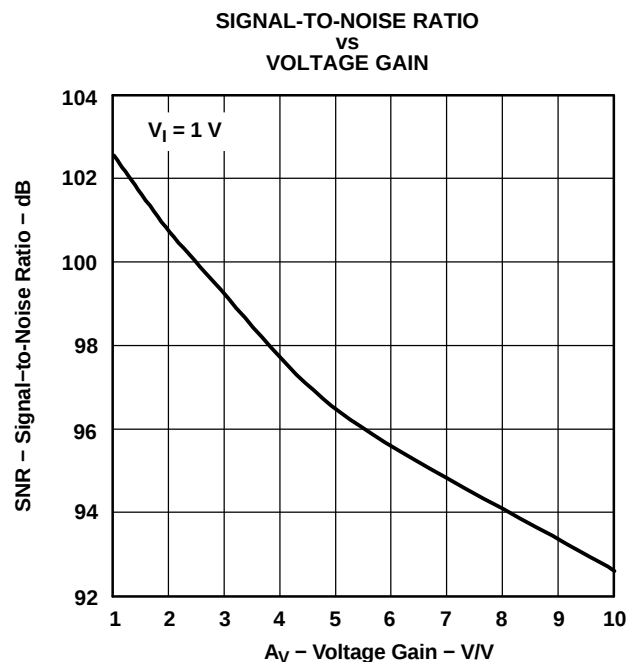


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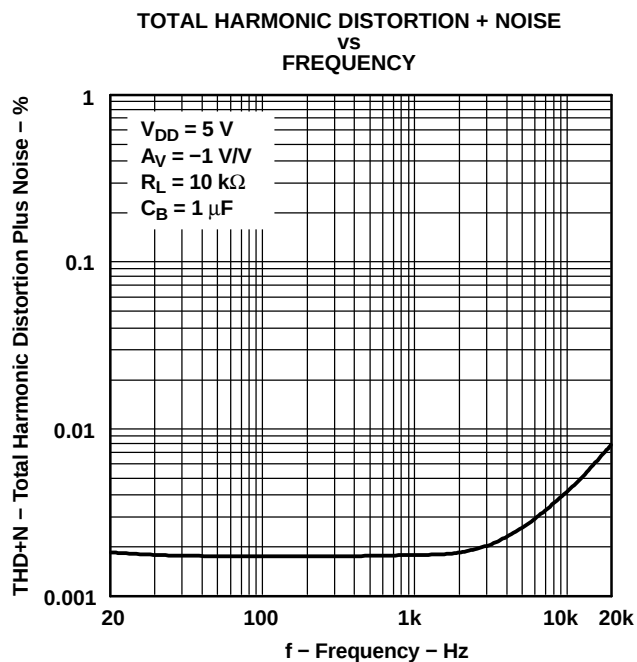


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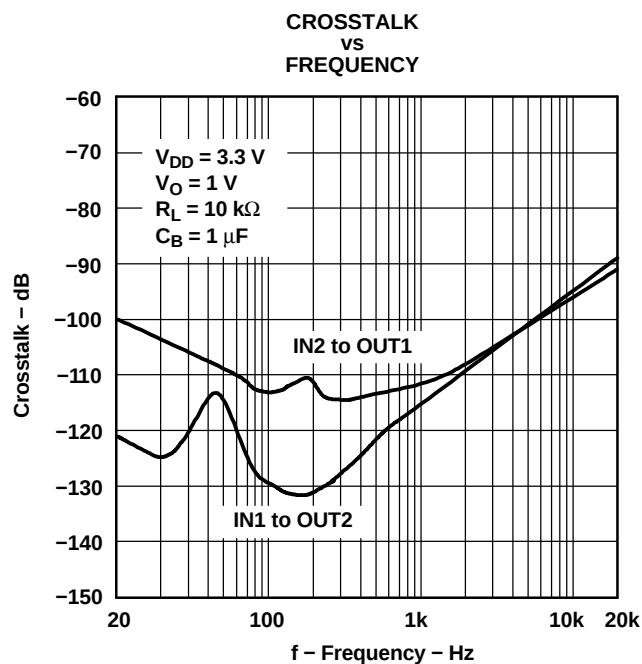


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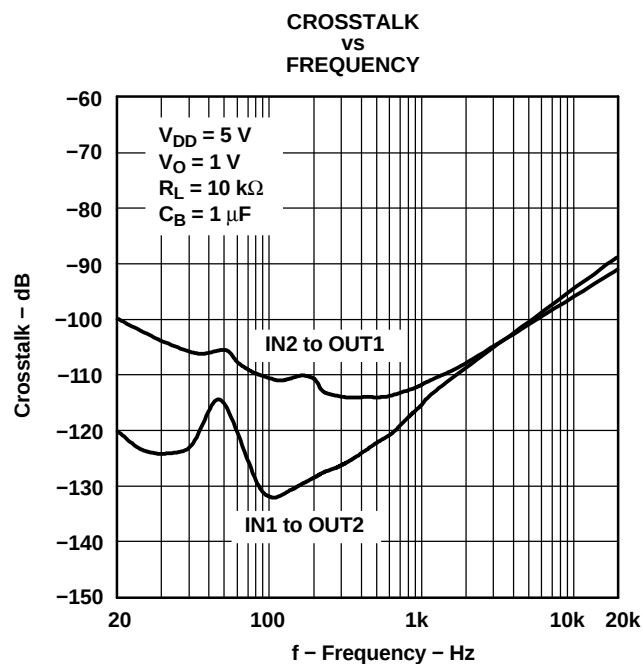


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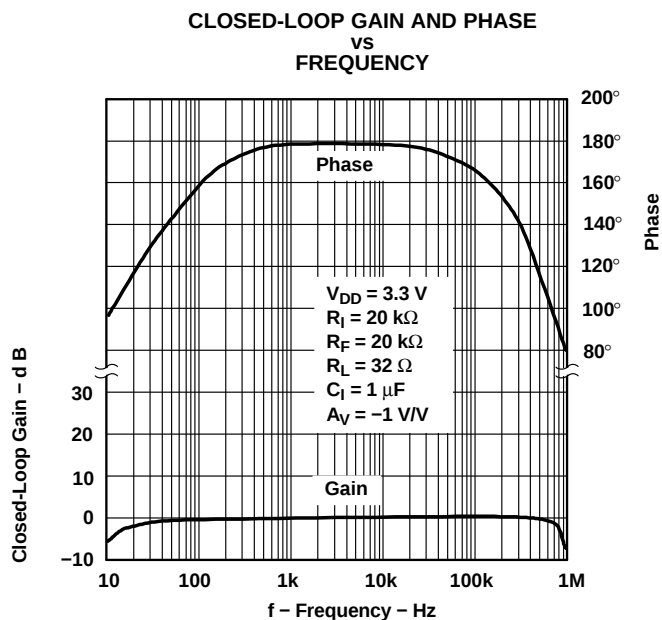


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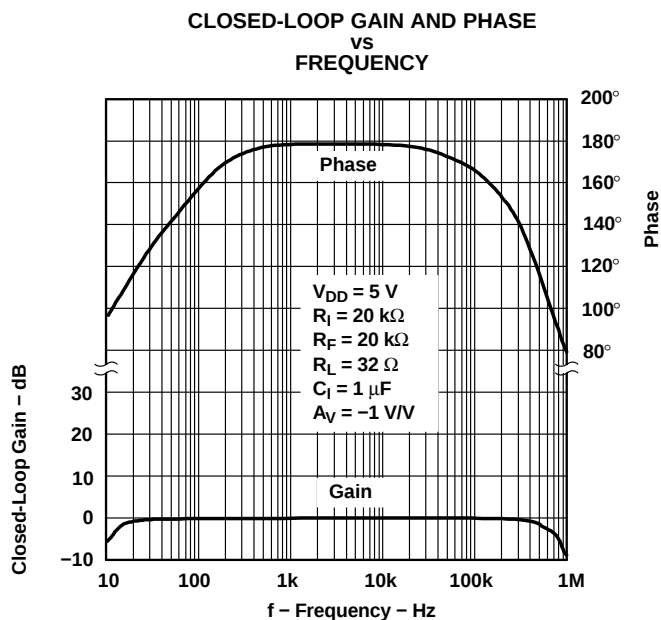


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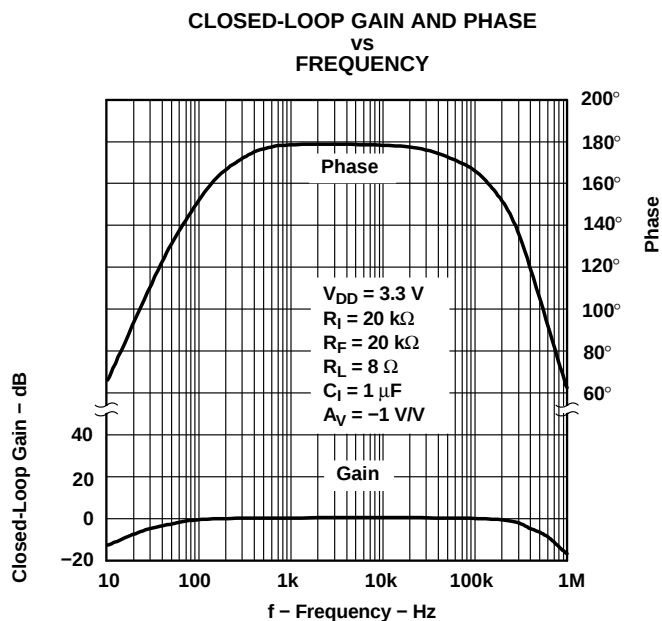


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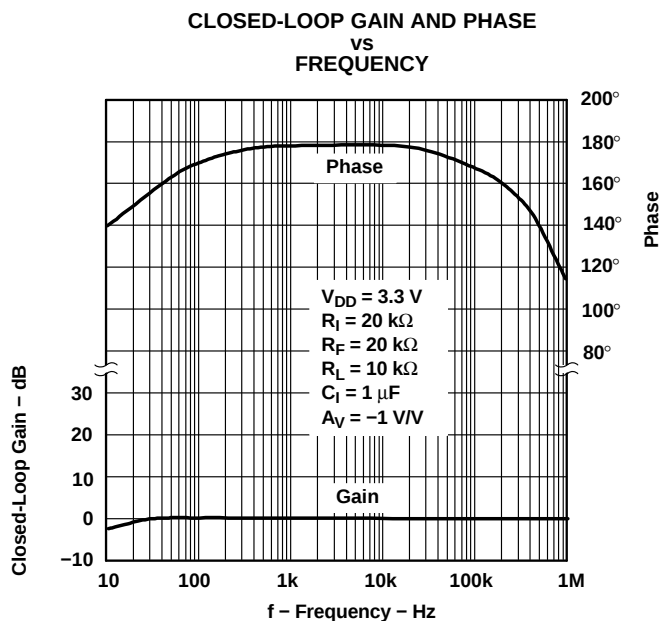


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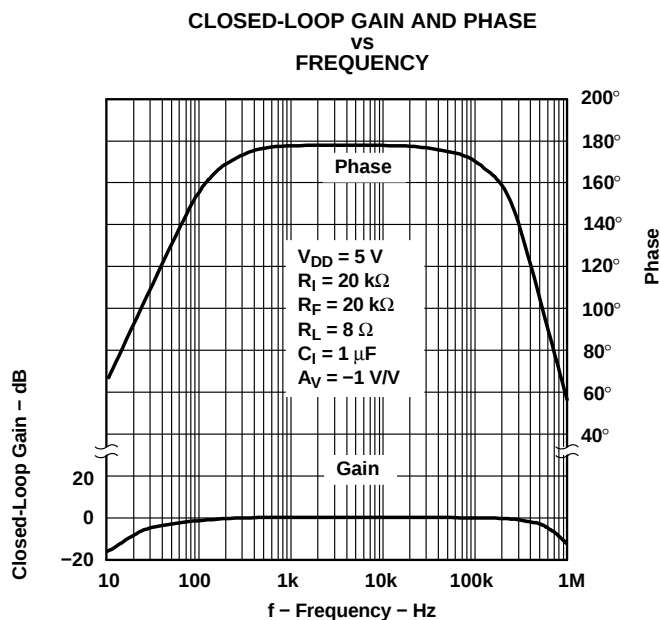


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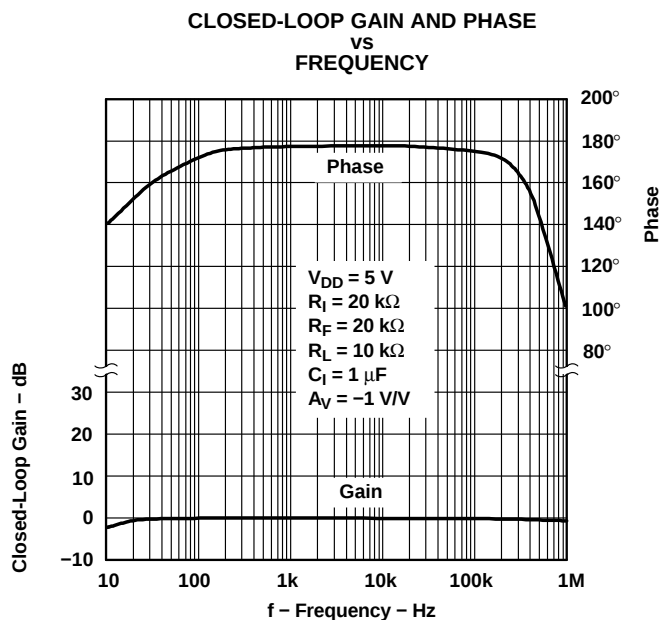


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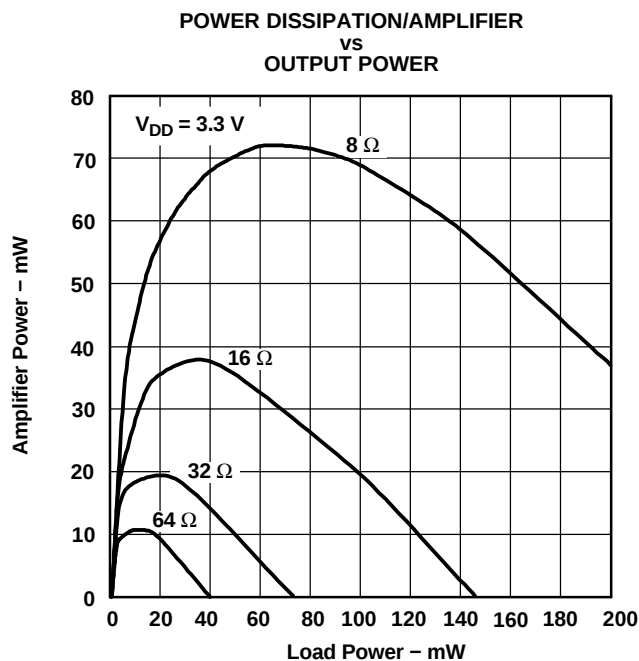


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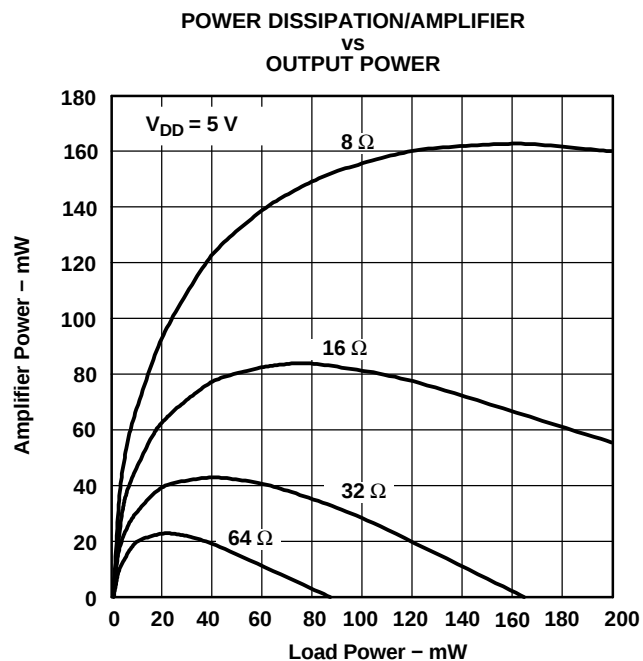


Figure 46.

APPLICATION INFORMATION

GAIN SETTING RESISTORS, R_f and R_i

The gain for the TPA102 is set by resistors R_f and R_i according to Equation 1.

$$\text{Gain} = - \left(\frac{R_f}{R_i} \right) \quad (1)$$

Given that the TPA102 is a MOS amplifier, the input impedance is very high. Consequently input leakage currents are not generally a concern. However, noise in the circuit increases as the value of R_f increases. In addition, a certain range of R_f values is required for proper start-up operation of the amplifier. Considering these factors, it is recommended that the effective impedance seen by the inverting node of the amplifier be set between 5 k Ω and 20 k Ω . The effective impedance is calculated using Equation 2.

$$\text{Effective Impedance} = \frac{R_f R_i}{R_f + R_i} \quad (2)$$

For example, if the input resistance is 20 k Ω and the feedback resistor is 20 k Ω , the gain of the amplifier is -1, and the effective impedance at the inverting terminal is 10 k Ω , a value within the recommended range.

For high performance applications, metal-film resistors are recommended because they tend to have lower noise levels than carbon resistors. For values of R_f above 50 k Ω , the amplifier tends to become unstable due to a pole formed from R_f and the inherent input capacitance of the MOS input structure. For this reason, a small compensation capacitor of approximately 5 pF should be placed in parallel with R_f . This, in effect, creates a low-pass filter network with the cutoff frequency defined by Equation 3.

$$f_{c(\text{lowpass})} = \frac{1}{2\pi R_f C_F} \quad (3)$$

For example, if R_f is 100 k Ω and C_F is 5 pF then $f_{c(\text{lowpass})}$ is 318 kHz, which is well outside the audio range.

INPUT CAPACITOR, C_i

In the typical application, an input capacitor, C_i , is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case, C_i and R_i form a high-pass filter with the corner frequency determined in Equation 4.

$$f_{c(\text{highpass})} = \frac{1}{2\pi R_i C_i} \quad (4)$$

The value of C_i directly affects the bass (low frequency) performance of the circuit. Consider the example where R_i is 20 k Ω and the specification calls for a flat bass response down to 20 Hz. Equation 4 is reconfigured as Equation 5.

$$C_i = \frac{1}{2\pi R_i f_{c(\text{highpass})}} \quad (5)$$

In this example, C_i is 0.40 μ F, so one would likely choose a value in the range of 0.47 μ F to 1 μ F. A further consideration for this capacitor is the leakage path from the input source through the input network formed by R_i , C_i , and the feedback resistor (R_f) to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high-gain applications (gain >10). For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, connect the positive side of the capacitor to the amplifier input in most applications. The dc level there is held at $V_{DD}/2$ —likely higher than the source dc level. It is important to confirm the capacitor polarity in the application.

POWER SUPPLY DECOUPLING, $C_{(s)}$

The TPA102 is a high-performance CMOS audio amplifier that requires adequate power-supply decoupling to minimize the output total harmonic distortion (THD). Power-supply decoupling also prevents oscillations when long lead lengths are used between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1 μ F, placed as close as possible to the device V_{DD} lead, works best. For filtering lower-frequency noise signals, a larger aluminum electrolytic capacitor of 10 μ F or greater placed near the power amplifier is recommended.

MIDRAIL BYPASS CAPACITOR, $C_{(B)}$

The midrail bypass capacitor, $C_{(B)}$, serves several important functions. During start up, $C_{(B)}$ determines the rate at which the amplifier starts up. This helps to push the start-up pop noise into the subaudible range (so low it can not be heard). The second function is to reduce noise produced by the power supply caused by coupling into the output drive signal. This noise is from the midrail generation circuit internal to the amplifier. The capacitor is fed from a 230-k Ω source inside the amplifier. To keep the start-up pop as low as possible, maintain the relationship shown in Equation 6.

$$\frac{1}{(C_{(B)} \times 230 \text{ k}\Omega)} \leq \frac{1}{(C_i R_i)} \quad (6)$$

Consider an example circuit where $C_{(B)}$ is 1 μF , C_i is 1 μF , and R_i is 20 k Ω . Substituting these values into the equation 9 results in: $6.25 \leq 50$ which satisfies the rule. Bypass capacitor, $C_{(B)}$, values of 0.1 μF to 1 μF ceramic or tantalum low-ESR capacitors are recommended for the best THD and noise performance.

OUTPUT COUPLING CAPACITOR, $C_{(C)}$

In a typical single-supply, single-ended (SE) configuration, an output coupling capacitor ($C_{(C)}$) is required to block the dc bias at the output of the amplifier, thus preventing dc currents in the load. As with the input coupling capacitor, the output coupling capacitor and impedance of the load form a high-pass filter governed by Equation 7.

$$f_c = \frac{1}{2\pi R_L C_{(C)}} \quad (7)$$

The main disadvantage, from a performance standpoint, is that the typically-small load impedance drives the low-frequency corner higher. Large values of $C_{(C)}$ are required to pass low frequencies into the load. Consider the example where a $C_{(C)}$ of 68 μF is chosen and loads vary from 32 Ω to 47 k Ω . Table 1 summarizes the frequency response characteristics of each configuration.

Table 1. Common Load Impedances vs Low-Frequency Output Characteristics in SE Mode

R_L	$C_{(C)}$	LOWEST FREQUENCY
32 Ω	68 μF	73 Hz
10,000 Ω	68 μF	0.23 Hz
47,000 Ω	68 μF	0.05 Hz

As Table 1 indicates, headphone response is adequate, and drive into line level inputs (a home stereo for example) is very good.

The output coupling capacitor required in single-supply SE mode also places additional constraints on the selection of other components in the amplifier circuit. With the rules described earlier still valid, add the following relationship:

$$\frac{1}{(C_{(B)} \times 230 \text{ k}\Omega)} \leq \frac{1}{(C_i R_i)} \ll \frac{1}{R_L C_{(C)}} \quad (8)$$

USING LOW-ESR CAPACITORS

Low-ESR capacitors are recommended throughout this application. A real capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance, the more the real capacitor behaves like an ideal capacitor.

5-V VERSUS 3.3-V OPERATION

The TPA102 was designed for operation over a supply range of 2.5 V to 5.5 V. This data sheet provides full specifications for 5-V and 3.3-V operation, since these are considered to be the two most common supply voltages. There are no special considerations for 3.3-V versus 5-V operation as far as supply bypassing, gain setting, or stability. The most important consideration is that of output power. Each amplifier in the TPA102 can produce a maximum voltage swing of $V_{DD} - 1 \text{ V}$. This means, for 3.3-V operation, clipping starts to occur when $V_{O(PP)} = 2.3 \text{ V}$ as opposed when $V_{O(PP)} = 4 \text{ V}$ while operating at 5 V. The reduced voltage swing subsequently reduces maximum output power into the load before distortion becomes significant.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPA102DGN	ACTIVE	MSOP-Power PAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPA102DGNG4	ACTIVE	MSOP-Power PAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPA102DGNR	ACTIVE	MSOP-Power PAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPA102DGNRG4	ACTIVE	MSOP-Power PAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPA102EVM	OBSOLETE			0		TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA102DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

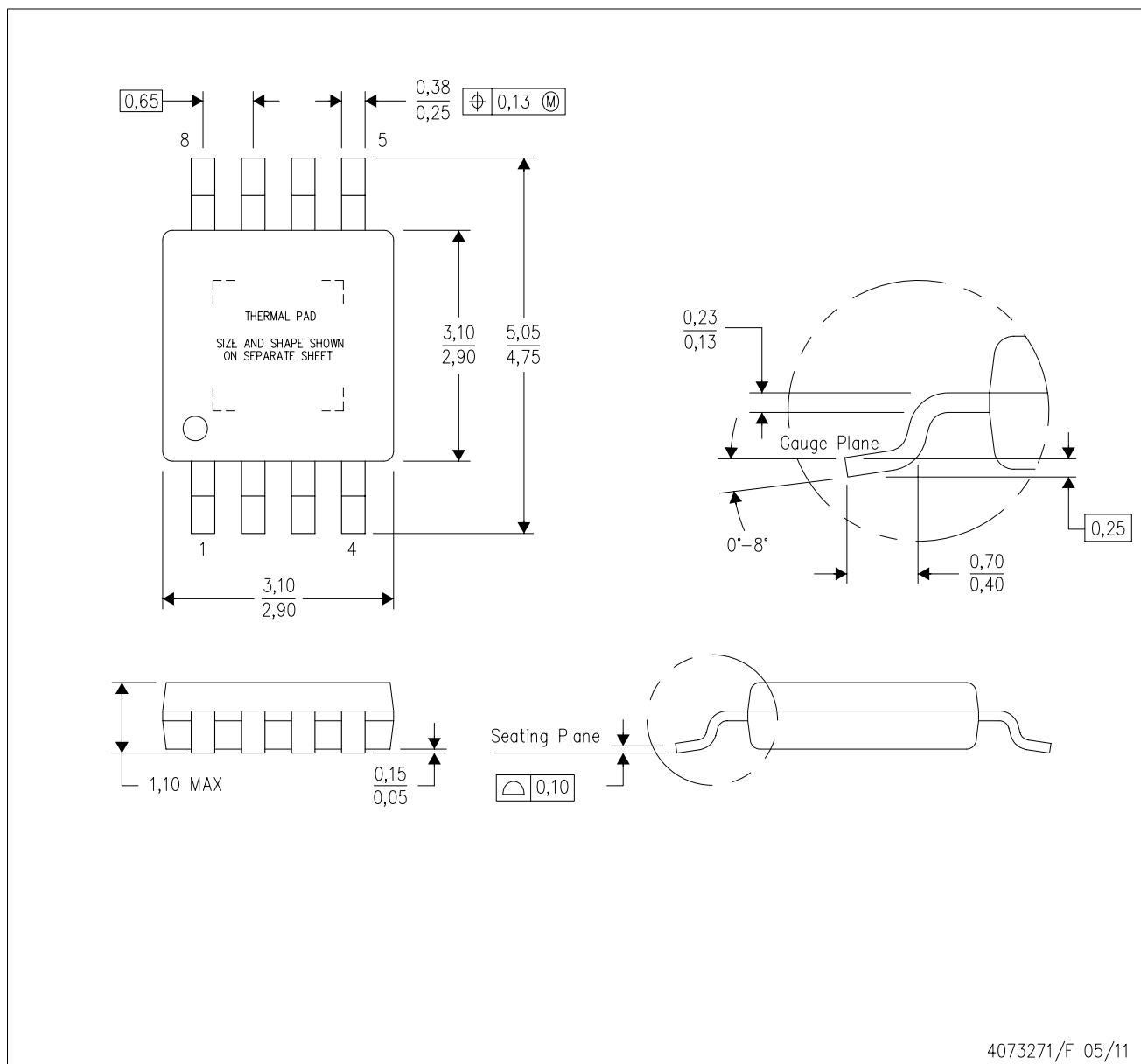


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA102DGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Falls within JEDEC MO-187 variation AA-T

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